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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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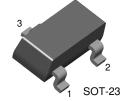




### **FJV4110R**

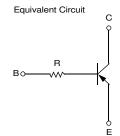
### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=10K $\Omega$ )
- Complement to FJV3110R



1. Base 2. Emitter 3. Collector





## **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	-40	V
$V_{CEO}$	Collector-Emitter Voltage	-40	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	200	mW
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}$ = -100 $\mu$ A, $I_{E}$ =0	-40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{E}$ = -1mA, $I_{B}$ =0	-40			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ = -30V, $I_{E}$ =0			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -5V, $I_{C}$ = -1mA	100		600	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C$ = -10mA, $I_B$ = -1mA			-0.3	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0 f=1MHz		5.5		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -10V, I <sub>C</sub> = -5mA		200		MHz
R	Input Resistor		7	10	13	ΚΩ

# **Typical Characteristics**

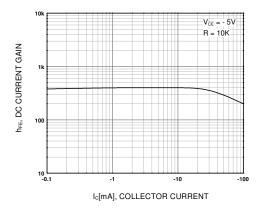


Figure 1. DC current Gain

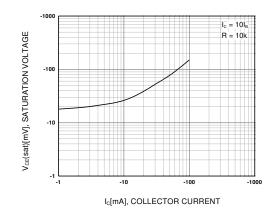


Figure 2. Collector-Emitter Saturation

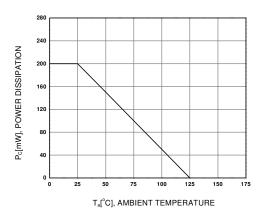
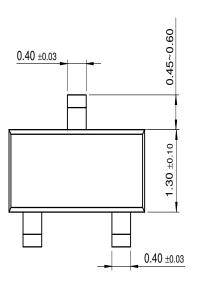
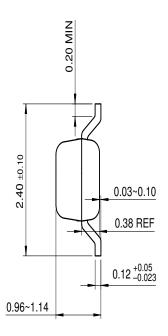


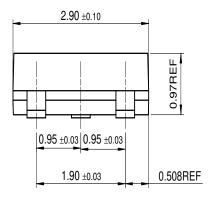
Figure 3. Power Derating

## **Package Dimensions**

## SOT-23







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EnSigna™	I <sup>2</sup> C™	OCX™	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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Rev. I1

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Datasheet Identification	Product Status	Definition
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